

### Attorney's Docket No.: 0797 010005 / US2941D1D1D1

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Kusumoto, et al.

Art Unit:

Unknown

Serial No.:

09/941,367

Examiner:

Unknown

Filed

August 28, 2001

Title

METHOD FOR PRODUCING INSULATED GATE THIN FILM

SEMICONDUCTOR DEVICE

Commissioner for Patents Washington, D.C. 20231

## TRANSMITTAL LETTER AND PETITION FOR AUTOMATIC EXTENSION

Correspondence relating to this application is enclosed. The required fees are computed below. Please apply any charges not covered, or any credits, to Deposit Account No. 06-1050.

Total Claims

108

80

28

\$504

Independent

23

16

\$588

Claims

First Presentation of Multiple Dependent

\$280

TOTAL FEE DUE

\$1372

A check for \$1372 is attached.

Respectfully submitted,

Act. 10,2

Bing Ai

43,312 Reg. No.

Fish & Richardson P.C. PTO Customer No. 20985

4350 La Jolla Village Drive, Suite 500

San Diego, California 92122 Telephone: (858) 678-5070

Facsimile: (858) 678-5099

ECHNOLOGY CENTER 2800

10139328.doc

## CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR \$1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231. October 10, 2001

Date of Deposit

Signature

Norman Green

Printed Name of Typed or Person Certificate



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## PRELIMINARY AMENDMENT

Prior to examination, please amend the application as THWOLOGY CENTER 280

In the claims:

Add claims 21-30 as follows:

follows:

-- 21. (New) A method for manufacturing a semiconductor device, said method comprising the steps of:

forming a semiconductor layer over a substrate;

irradiating said semiconductor layer with a CW laser beam to crystallize said semiconductor layer; and

patterning the crystallized semiconductor layer to form an active layer including a channel region,

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01 FC:103 02 FC:102 03 FC:104 504.00 OP 588.00 OP 280.00 OP